

GENERAL PURPOSE APPLICATION.

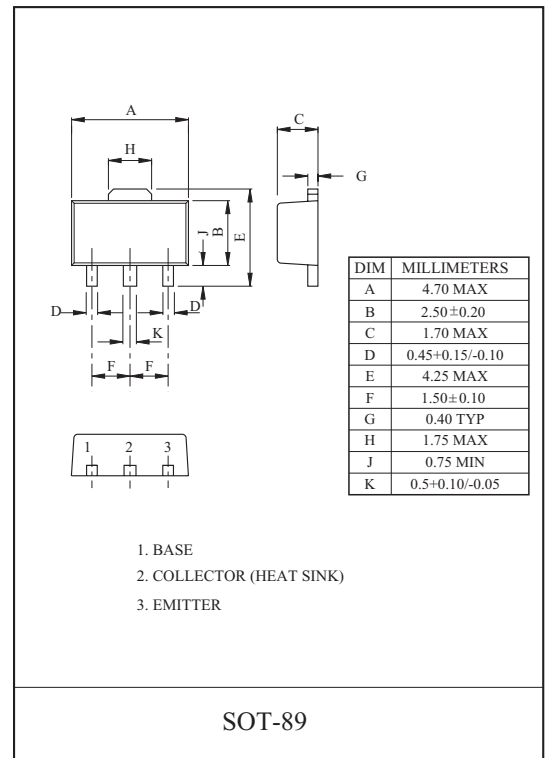
### FEATURES

- 1W (Mounted on Ceramic Substrate).
- Small Flat Package.
- Complementary to KTA1662.

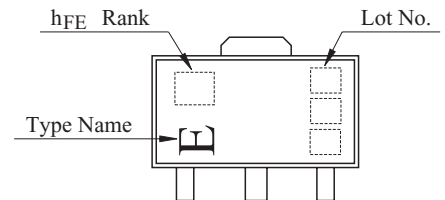
### MAXIMUM RATING (Ta=25 °C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	80	V
Collector-Emitter Voltage	$V_{CEO}$	80	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	400	mA
Base Current	$I_B$	80	mA
Collector Power Dissipation	$P_C$	500	mW
	$P_C^*$	1	W
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{stg}$	-55 ~ 150	°C

$P_C^*$  : KTA1662 mounted on ceramic substrate (250mm<sup>2</sup>x0.8t)



### Marking



### ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=80V, I_E=0$	-	-	100	nA
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=5V, I_C=0$	-	-	100	nA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=10mA, I_B=0$	80	-	-	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE}=2V, I_C=50mA$	70	-	240	
	$h_{FE(2)}$	$V_{CE}=2V, I_C=200mA$	50	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=200mA, I_B=20mA$	-	-	0.4	V
Base-Emitter Voltage	$V_{BE}$	$V_{CE}=2V, I_C=5mA$	0.55	-	0.8	V
Transition Frequency	$f_T$	$V_{CE}=10V, I_C=10mA$	-	100	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=10V, I_E=0, f=1MHz$	-	10	-	pF

Note :  $h_{FE}$  Classification O:70~140, Y:120~240

# KTC4374

